60V N-Ch Power MOSFET

DS(on),typ			Ω
DS(on),typ			Ω

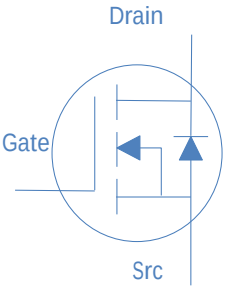
Feature

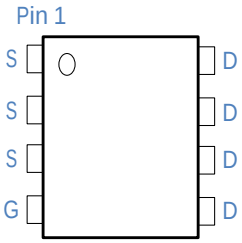
- High Speed Power Switching, Logic Level
- Enhanced Body diode dv/dt capability
- Enhanced Avalanche Ruggedness
- 100% UIS Tested, 100% Rg Tested
- Lead Free, Halogen Free

Application

- Synchronous Rectification in SMPS
- Hard Switching and High Speed Circuit
- DC/DC in Telecoms and Inductrial

DFN3.3x3.3

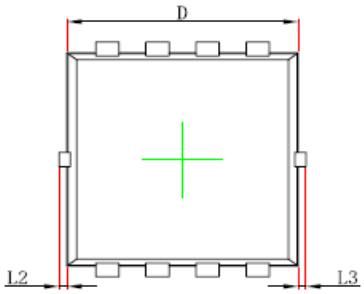




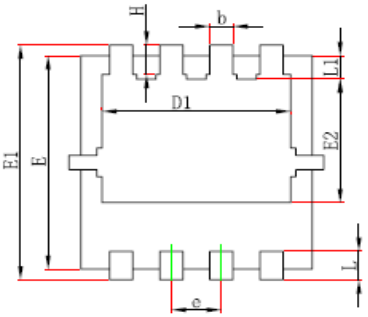
=25 (unless otherwise specified)

		=25		
		=100		
		=25		
Avalanche Energy, Single Pulse	E	=25		
Power Dissipation		=25		W
Operating and Storage Temperature				

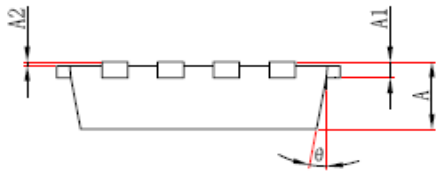
Thermal Resistance Junction-Ambient	θ		/W
Thermal Resistance Junction-Case	θ		/W



Top View



Bottom View



Side View